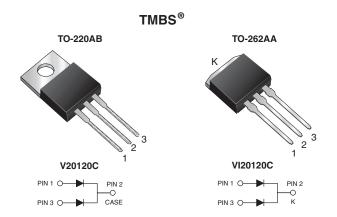
Vishay General Semiconductor

Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.54$ V at $I_F = 5$ A



| PRIMARY CHARACTERISTICS | | | | | |
|-------------------------|--------------------|--|--|--|--|
| I _{F(AV)} | 2 x 10 A | | | | |
| V _{RRM} | 120 V | | | | |
| I _{FSM} | 120 A | | | | |
| V_F at $I_F = 10$ A | 0.64 V | | | | |
| T _J max. | 150 °C | | | | |
| Package | TO-220AB, TO-262AA | | | | |
| Diode variation | Common cathode | | | | |

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- HALOGEN Solder dip 275 °C max. 10 s, per JESD 22-B106 FREE
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

w.vishav.com/doc?91000

Polarity: as marked

Mounting Torque: 10 in-lbs max.

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|-------------------------------------------------------------------------------------------------|------------|-----------------------------------|----------|----------|------|--|--|
| PARAMETER | | SYMBOL | V20120C | VI20120C | UNIT | | |
| Max. repetitive peak reverse voltage | | V _{RRM} | 120 | | V | | |
| Max. average forward rectified current (fig. 1) | per device | 1 | 20 10 | | A | | |
| | per diode | I _{F(AV)} | | | | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | | I _{FSM} | 120 | | A | | |
| Voltage rate of change (rated V _R) | | dV/dt | 10 000 | | V/µs | | |
| Operating junction and storage temperature range | | T _J , T _{STG} | -40 to | +150 | °C | | |

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RoHS COMPLIANT





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| ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | | | |
|-----------------------------------------------------------------------------------|-----------------------------------------------------|---------------------------|---------------------------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 5 A | - T _A = 25 °C | - V _F ⁽¹⁾ | 0.62 | - | V | |
| | $I_F = 10 \text{ A}$ | | | 0.81 | 0.90 | | |
| | $I_F = 5 A$ | – T _A = 125 °C | | 0.54 | - | | |
| | I _F = 10 A | | | 0.64 | 0.72 | | |
| Reverse current per diode | V _R = 90 V | T _A = 25 °C | I _R ⁽²⁾ | 8 | - | μA | |
| | | T _A = 125 °C | | 6 | - | mA | |
| | $V_{R} = 120 V$ $T_{A} = 25 °C$ $T_{A} = 125 °C$ | | | - | 700 | μA | |
| | | | 14 | 45 | mA | | |

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 $\,\%$ duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|--------------------------------------------------------------------------------|---------------------|---------|----------|------|--|
| PARAMETER | SYMBOL | V20120C | VI20120C | UNIT | |
| Typical thermal resistance per diode | $R_{	ext{	heta}JC}$ | 2.8 | | °C/W | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-220AB | V20120C-M3/4W | 1.88 | 4W | 50/tube | Tube | | |
| TO-262AA | VI20120C-M3/4W | 1.45 | 4W | 50/tube | Tube | | |



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

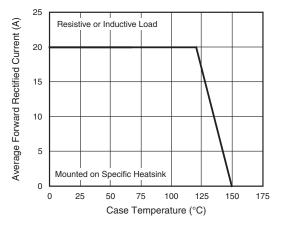


Fig. 1 - Maximum Forward Current Derating Curve

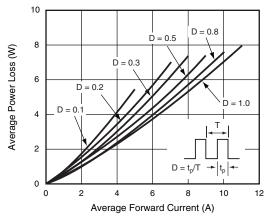


Fig. 2 - Forward Power Loss Characteristics Per Diode

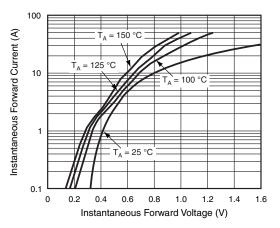


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

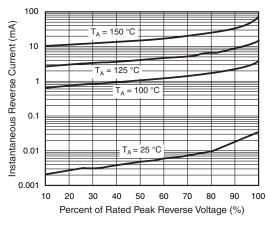


Fig. 4 - Typical Reverse Characteristics Per Diode

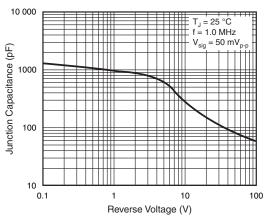


Fig. 5 - Typical Junction Capacitance Per Diode

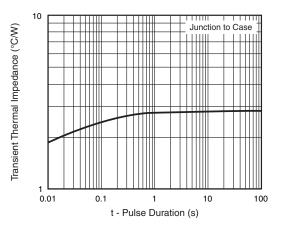


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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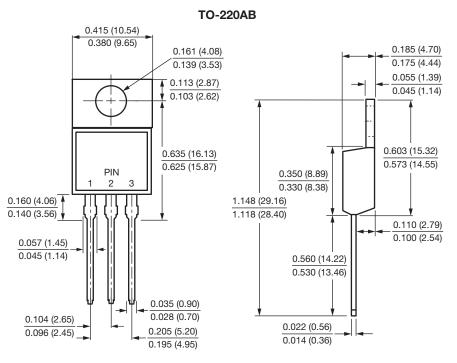
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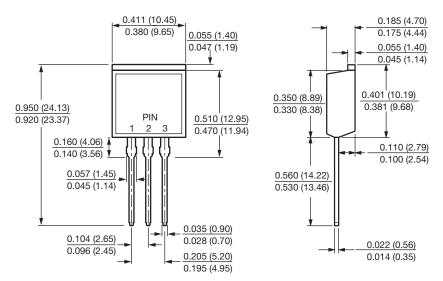
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA





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